Docket No.

270968US2X PCT

IN THE UNITED STATES PA

IN RE APPLICATION OF: Shinsuke HARADA, et al.

SERIAL NO:

O: 10/531,582 ****

GAU:

FILED:

April 18, 2005

EXAMINER:

DEMARK OFFICE

FOR:

SILICON CARBIDE SEMICONDUCTOR DEVICE AND ITS MANUFACTURING METHOD

INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR 1.97

COMMISSIONER FOR PATENTS ALEXANDRIA, VIRGINIA 22313

SIR:

Applicant(s) wish to disclose the following information.

REFERENCES

The applicant(s) wish to make of record the references listed on the attached form PTO-1449. Copies of the listed references are attached, where required, as are either statements of relevancy or any readily available English translations of pertinent portions of any non-English language references.

☐ A check or credit card payment form is attached in the amount required under 37 CFR §1.17(p).

RELATED CASES

Attached is a list of applicant's pending application(s), published application(s) or issued patent(s) which may be related to the present application. In accordance with the waiver of 37 CFR 1.98 dated September 21, 2004, copies of the cited pending applications are not provided. Cited published and/or issued patents, if any, are listed on the attached PTO form 1449.

☐ A check or credit card payment form is attached in the amount required under 37 CFR §1.17(p).

CERTIFICATION

☐ Each item of information contained in this information disclosure statement was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this statement.

□ No item of information contained in this information disclosure statement was cited in a communication from a foreign patent office in a counterpart foreign application or, to the knowledge of the undersigned, having made reasonable inquiry, was known to any individual designated in 37 CFR §1.56(c) more than three months prior to the filing of this statement.

DEPOSIT ACCOUNT

Please charge any additional fees for the papers being filed herewith and for which no check or credit card payment is enclosed herewith, or credit any overpayment to deposit account number <u>15-0030</u>. A duplicate copy of this sheet is enclosed.

Respectfully submitted,

OBLON, SPIVAK, McCLELLAND, MAIER & NEUSTADT, P.C.

Marvin J. Spivak

Registration No. 24,913

Surinder Sachar

Registration No. 34,423

Customer Number

22850

Tel. (703) 413-3000 Fax. (703) 413-2220 (OSMMN 05/03)

Form PTO 1449		U.S. DEPARTMENT		ATTY DOCKET NO. 270968US2X PCT		SERIAL NO. 10/531,582	
(Modified)		PATENT AND TRA	DEMARK OFFICE				
				APPLICANT			
LIST OF	REFE	RENCES CITED BY AF	PLICANT	Shinsuke HARADA, et al.			
				FILING DATE		GROUP	
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				U.S. PATENT DOCUMENTS			
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		DOCUMENT	DATE	COUNTRY		TRANSLATION	
		NUMBER				YES	
	AO	2001-119025	04/27/01	JP (with English abstract)	-		NO
	AP	2000-150875	05/30/00	JP (with English abstract)			NO
	AQ	1-144683	06/06/89	JP (with English abstract)			NO
	AR	61-013667	01/21/86	JP (English abstract only)			NO
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		OTHER R	EFERENCES (Including Author, Title, Date, Pertinent	– t Pages, e	tc.)	
		CAPANO, M.A. et al.	"lonization ene	rgies and electron mobilities in phosphore	us- and nit	rogen- impl	lanted 4H-silicon carbide",
	AW	CAPANO, M.A. et al. "Ionization energies and electron mobilities in phosphorus- and nitrogen- implanted 4H-silicon carbide" Journal of Applied Physics, vol. 87, no. 12, pages 8773-8777 2000					
	AX	HARADA, Shinsuke e Letters, vol. 22, no. 6, 2001		nnel Mobility in Normally-Off 4H-SiC Buri 4	ed Channe	MOSFET	's", IEEE Electron Device
	AY						
	AZ				Addi	tional Refe	rences sheet(s) attached
Examiner					Date Considered		
*Examiner: In conformance	itial if r	eference is considered ot considered. Include o	, whether or no opy of this form	t citation is in conformance with MPEP 60 with next communication to applicant.	09; Draw li	ne through	citation if not in

U.S. PCT Application Serial No.: 10/531,582 Docket No.: 270968US2X PCT

STATEMENT OF RELEVANCY

1) References <u>AO-AR</u> have been cited in the International Search Report. Copies of these references are being submitted herewith only when not automatically provided by the International Searching Authority.
2) References have been cited in the corresponding Search Report A copy of these references is being submitted herewith.
3) References <u>AW, AX</u> are discussed in the specification. A copy of these references is being submitted here with.
4) References are additional prior art known to Applicant. A copy of these references is being submitted herewith.